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[Fairchild Semiconductor](#)
[RURP15100](#)

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15A, 1000V Ultrafast Diode

The RURP15100 is an ultrafast diode with soft recovery characteristics ($t_{rr} < 100ns$). It has a low forward voltage drop and is of silicon nitride passivated, ion-implanted, epitaxial construction.

This device is intended for use as a freewheel/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

Formerly developmental type TA09906.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURP15100	TO-220AC	RURP15100

NOTE: When ordering, use the entire part number.

Symbol



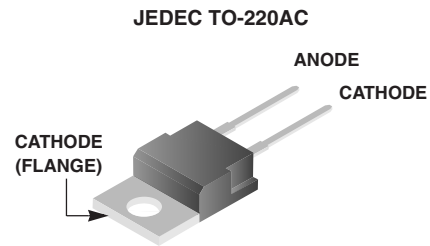
Features

- Ultrafast with Soft Recovery<100ns
- Operating Temperature175°C
- Reverse Voltage1000V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Packaging



Absolute Maximum Ratings $T_C = 25^\circ C$, Unless Otherwise Specified

	RURP15100	UNITS
Peak Repetitive Reverse Voltage	1000	V
Working Peak Reverse Voltage	1000	V
DC Blocking Voltage	1000	V
Average Rectified Forward Current ($T_C = 142^\circ C$)	15	A
Repetitive Peak Surge Current (Square Wave 20kHz)	30	A
Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	200	A
Maximum Power Dissipation	100	W
Avalanche Energy (See Figures 7 and 8)	20	mJ
Operating and Storage Temperature	-65 to 175	°C

RURP15100

Electrical Specifications $T_C = 25^\circ\text{C}$, Unless Otherwise Specified.

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V_F	$I_F = 15\text{A}$	-	-	1.8	V
	$I_F = 15\text{A}, T_C = 150^\circ\text{C}$	-	-	1.5	V
I_R	$V_R = 1000\text{V}$	-	-	100	μA
	$V_R = 1000\text{V}, T_C = 150^\circ\text{C}$	-	-	500	μA
t_{rr}	$I_F = 1\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	100	ns
	$I_F = 15\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	125	ns
t_a	$I_F = 15\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	75	-	ns
t_b	$I_F = 15\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	40	-	ns
$R_{\theta JC}$		-	-	1.5	$^\circ\text{C}/\text{W}$

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs , D = 2%).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 6), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 6).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

$R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

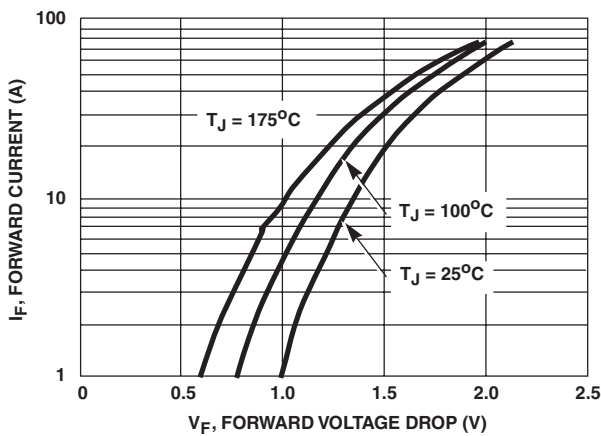


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

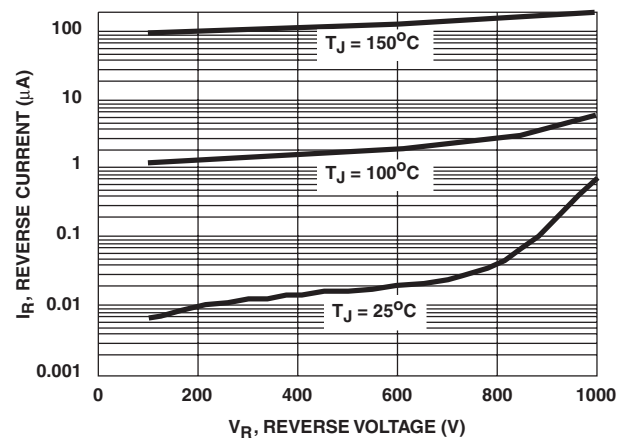


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

RURP15100

Typical Performance Curves (Continued)

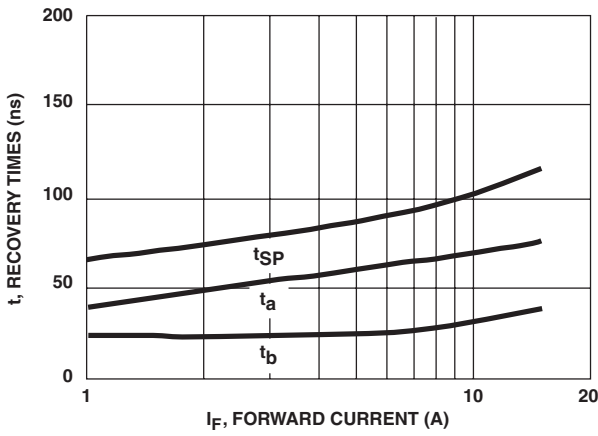


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

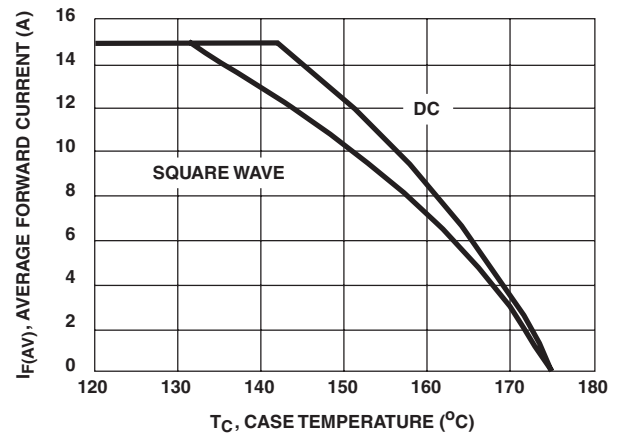


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

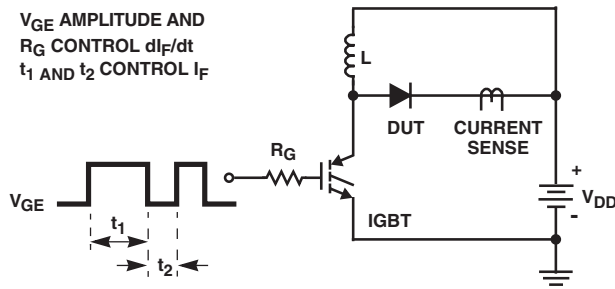


FIGURE 5. t_{rr} TEST CIRCUIT

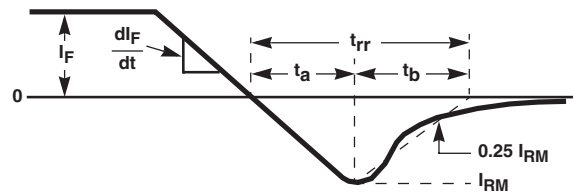


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

$I = 1A$
 $L = 40mH$
 $R < 0.1\Omega$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

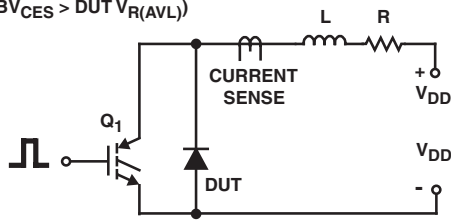


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

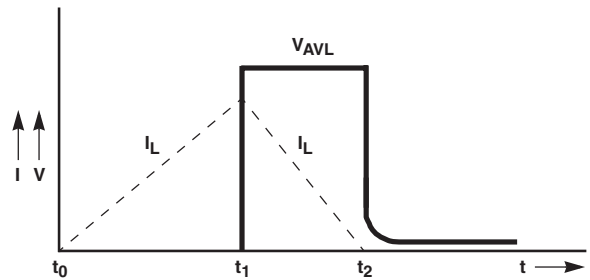


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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